

## **Overview**

The DL-3148-033 is index guided 635 nm (Typ.) AlGaInP laser diode with low threshold current and high operating temperature. The low threshold current and short wavelength are achieved by a strained multiple quantum well active layer. The lasing wavelength is 635nm which is 8 times brighter than that of 670nm lasers. The DL-3148-033 is suitable for applications such as bar-code scanners, laser printer, and other optical information systems.

#### Features

- · Short wavelength
- : 635 nm (Typ.) : Ith = 40 mA (Typ.)
- · Low threshold current
- High operating temperature  $:50^{\circ}$ C at 5 mW
- · Small package  $: 5.6 \text{ mm } \phi$

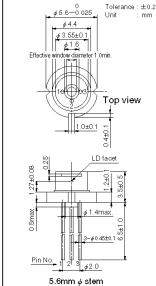
## Absolute Maximum Ratings at Tc=25°C

Parameter		Symbol	Ratings	Unit	
Light Output		Ро	5	mW	
Reverse Voltage	Laser PIN	VR	2 30	V	
Operating Temperature		Topr	-10 to +50	°C	
Storage Temperature		Tstg	-40 to +85	$^{\circ}\!$	

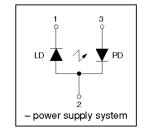
# Electrical and Optical Characteristics at Tc=25 °C

# d 5.6−0.025

**Package Dimensions** 



# **Electrical Connection**

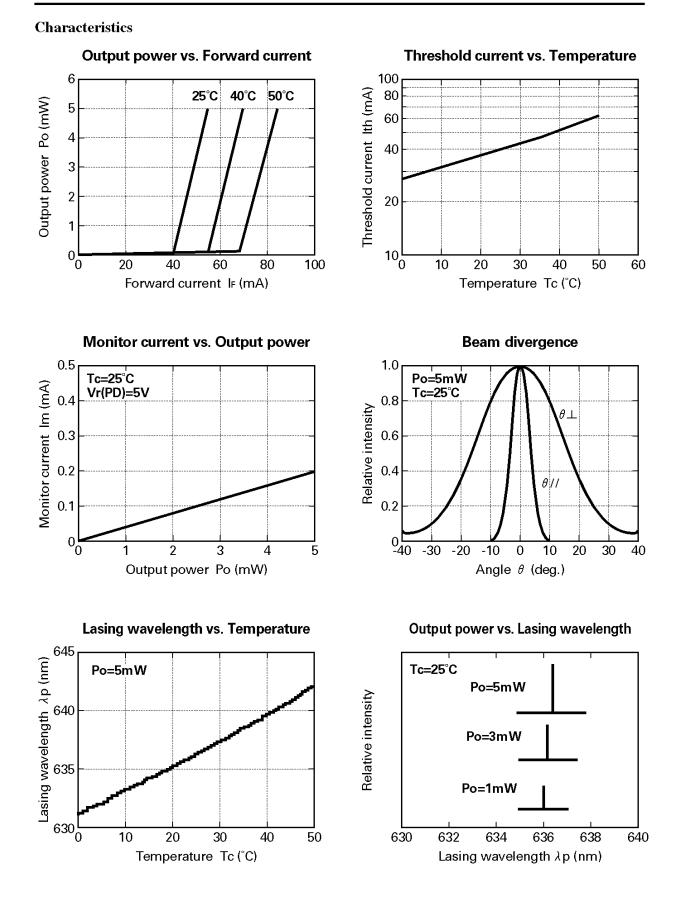


Para	neter	Symbol	Condition	Min.	Тур.	Max.	Unit
Threshold	d Current	Ith	CW	-	40	60	mA
Operating	g Current	Iop	Po=5mW	-	55	75	mA
Operating	g Voltage	Vop	Po=5mW	-	2.2	2.4	V
Lasing W	avelength	λp	Po=5mW	_	635	640	nm
Beam 💥 )	Perpendicular	$\theta \perp$	Po=5mW	25	35	40	deg.
Divergence	Parallel	θ //	Po=5mW	6	8	10	deg.
Off Axis	Perpendicular	$\Delta \theta \perp$	-	-	-	±3	deg.
Angle	Parallel	$\Delta  heta$ //	-	-	-	±3	deg.
Differential	Efficiency	dPo/dIop	-	-	0.4	-	mW/mA
Monitoring O	utput Current	Im	Po=5mW	0.1	0.2	0.5	mA
Astign	natism	As	Po=5mW	-	8	_	μm

※) Full angle at half maximum note : The above product specifications are subject to change without notice.

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# Precautionary instructions in handling gallium arsenic products

Special precautions must be taken in handling this product because it contains, gallium arsenic, which is designated as a toxic substance by law. Be sure to adhere strictly to all applicable laws and regulations enacted for this substance, particularly when it comes to disposal.

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